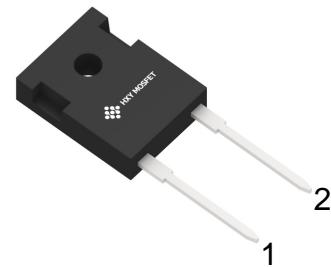




Features

- 1200-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F



TO-247-2L

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives



Part Number	Package	Qty(PCS)
NVDSH50120C	TO-247-2L	30

Maximum Ratings ($T_c = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
V_{RRM}	Repetitive Peak Reverse Voltage	1200	V	
V_{RSM}	Surge Peak Reverse Voltage	1200	V	
I_F	Continuous Forward Current	146.3 69.6 50	A	$T_c=25^\circ\text{C}$ $T_c=135^\circ\text{C}$ $T_c=152^\circ\text{C}$
I_{FRM}	Repetitive Peak Forward Surge Current	175	A	$T_c=25^\circ\text{C}$, $t_p = 10$ ms, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	350	A	$T_c=25^\circ\text{C}$, $t_p = 10$ ms, Half Sine Wave
P_{tot}	Power Dissipation	652 283	W	$T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$
T_J , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	°C	
	TO-220 Mounting Torque	1	Nm	M3 Screw
$\int i^2 dt$	$i^2 dt$ value	612.5	A^2s	$T_c=25^\circ\text{C}$, $t_p = 10$ ms, Half Sine Wave



Electrical Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
V_{DC}	DC Blocking Voltage	1200			V	
V_F	Forward Voltage		1.43 2	1.7 2.5	V	$I_F = 50 \text{ A} \quad T_J = 25^\circ\text{C}$ $I_F = 50 \text{ A} \quad T_J = 175^\circ\text{C}$
I_R	Reverse Current		35 132	100 600	μA	$V_R = 1200 \text{ V} \quad T_J = 25^\circ\text{C}$ $V_R = 1200 \text{ V} \quad T_J = 175^\circ\text{C}$
Q_c	Total Capacitive Charge		268		nC	$V_R = 800 \text{ V} \quad T_J = 25^\circ\text{C}$
C	Total Capacitance		4072 254 205		pF	$V_R = 0 \text{ V}, T_J = 25^\circ\text{C}, f = 1 \text{ MHz}$ $V_R = 400 \text{ V}, T_J = 25^\circ\text{C}, f = 1 \text{ MHz}$ $V_R = 800 \text{ V}, T_J = 25^\circ\text{C}, f = 1 \text{ MHz}$
E_c	Capacitance Stored Energy		138		μJ	$V_R = 800 \text{ V}$

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	0.23	$^\circ\text{C/W}$

Typical Performance

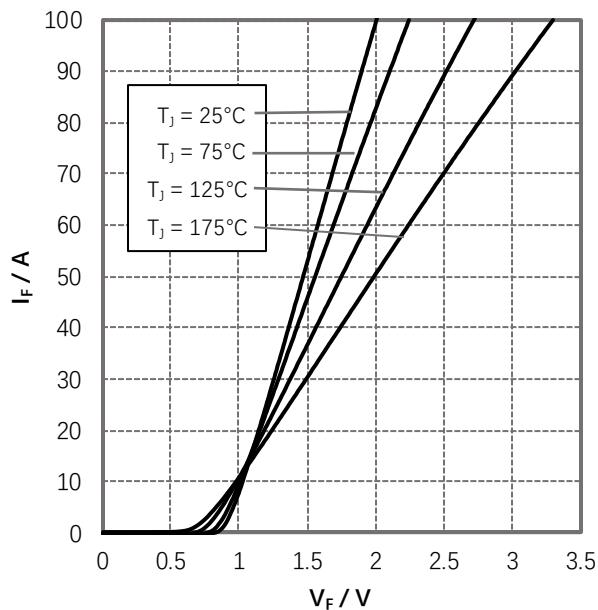


Figure 1. Forward Characteristics

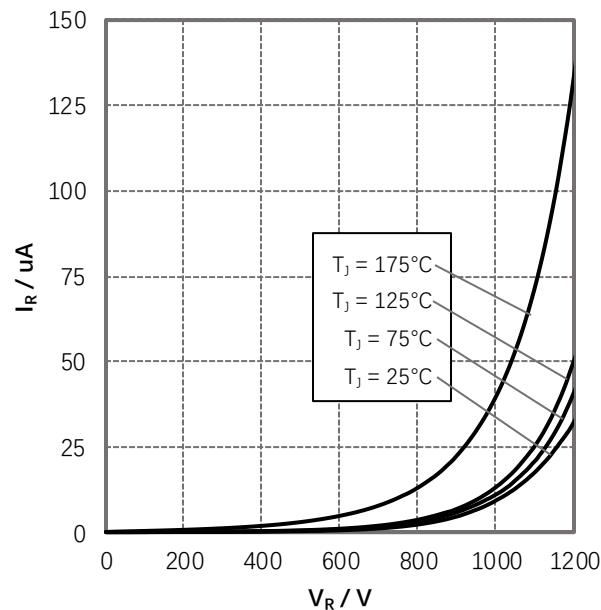
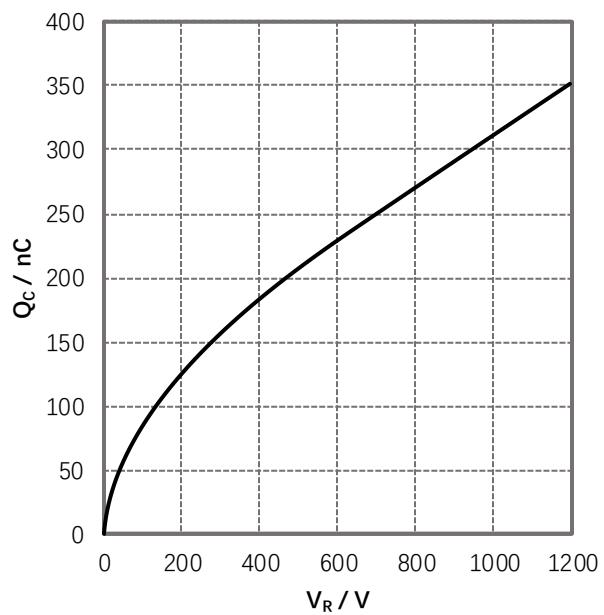
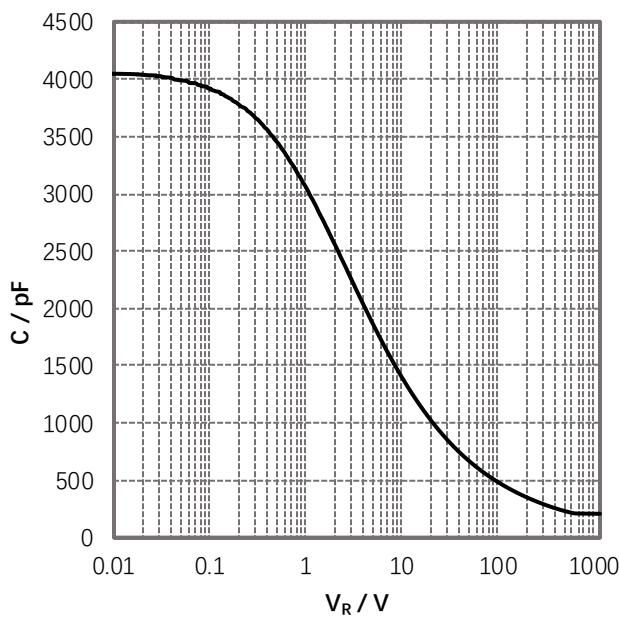
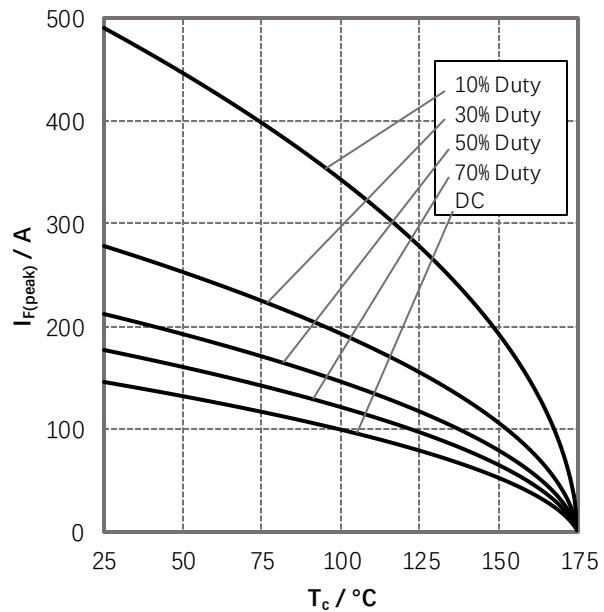
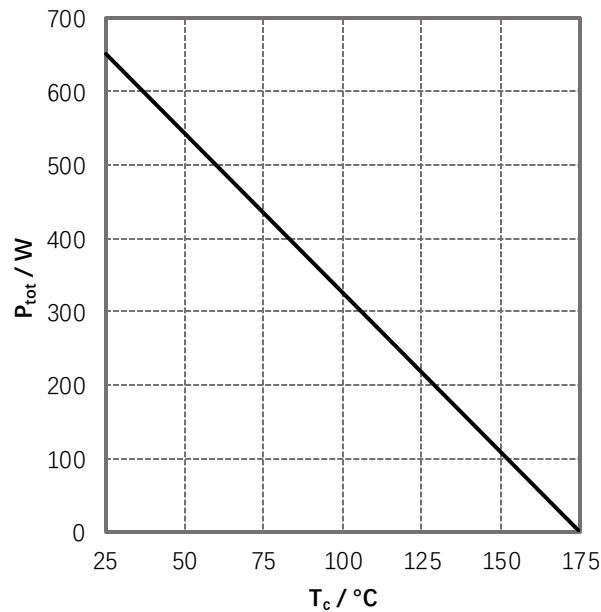


Figure 2. Reverse Characteristics



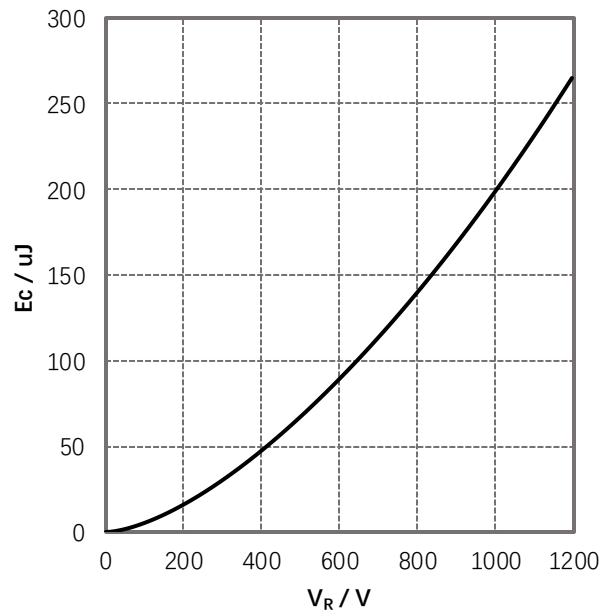


Figure 7. Capacitance Stored Energy

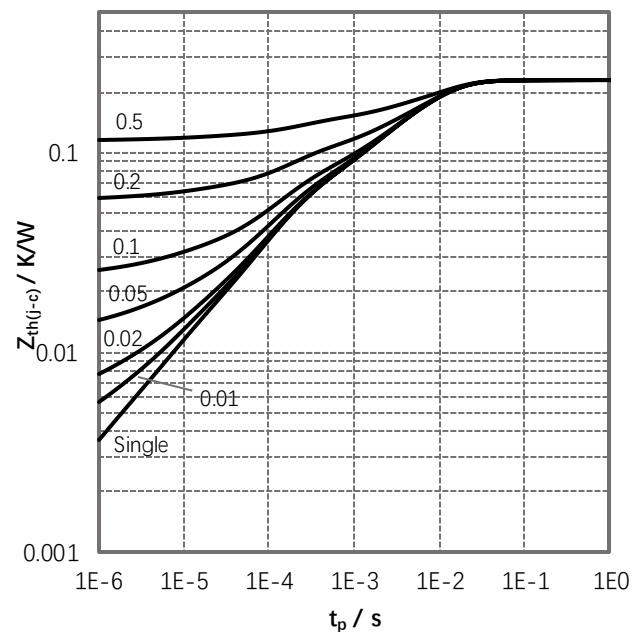
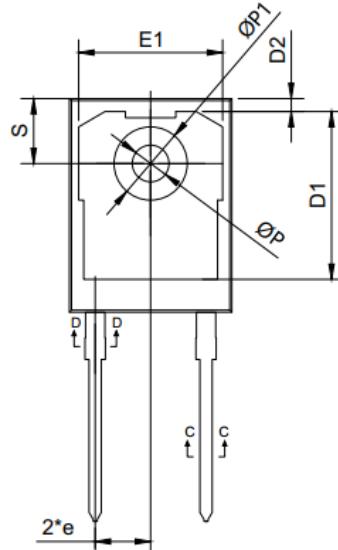
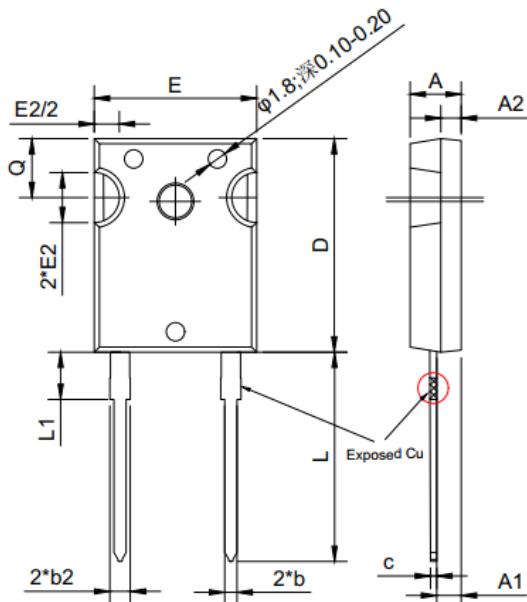


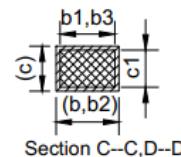
Figure 8. Transient Thermal Impedance



Package Information TO-247-2L



SYMBOL	DIMENSIONS		NOTES
	MIN	MAX	
A	4.83	5.21	
A1	2.29	2.55	
A2	1.50	2.49	
b	1.07	1.33	
b1	1.07	1.28	
b2	1.91	2.41	6
b3	1.91	2.34	
c	0.55	0.69	6
c1	0.55	0.65	
D	20.80	21.10	4
D1	16.25	17.65	5
D2	0.51	1.35	
E	15.75	16.13	4
E1	13.10	14.16	5
E2	3.68	5.49	3
e	5.44BSC		
L	19.81	20.32	6
L1	3.90	4.40	7
φP	3.51	3.65	
φP1	7.19REF		
Q	5.39	6.20	
S	6.04	6.30	



Note:
1. Package Reference: JEDEC TO-247, Variation AD.
2. All Dimensions Are In mm.
3. Solt Required, Notch May Be Rounded.
4. Dimension D & E Do Not Include Mold Flash. Mold Flash Shall Not Exceed 0.127mm Pre Side. These Dimensions Are Measured At The Outermost Extreme Of The Plastic Body.
5. Thermal Pad Contour Optional Within Dimension D1 & E1.
6. Lead Finish Uncontrolled In L1.
7. φP To Have A Maximum Draft Angle Of 1.5° To The Top Of The Part With A Maximum Hole Diameter Of 3.91mm.
8. Dimension "b2" And "b4" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.10mm Total In Excess Of "b2" And "b4" Dimension At Maximum Material Condition.



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